

BOWEI OXK40 OCXO Datasheet

<http://www.manuallib.com/bowei/oxk40-ocxo-datasheet.html>

Features

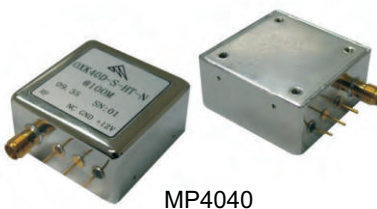
- Low phase noise
- High frequency stability
- Good performance under vibration
- SC cut crystal with TO-5 package
- External EMI filter

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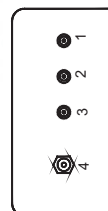
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Features

- Good performance under vibration
- Low phase noise
- External EMI filter
- High frequency stability
- SC cut crystal with TO-5 package



MP4040



Pin function

- 1:Power supply
- 2:Ground
- 3:Reference voltage output or NC
- 4:RF output

Electrical specification

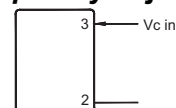
Parameter		Characteristic	
Power supply		+12V±5%(option+15V)	
Frequency range		40~120MHz	
Frequency stability		Vs. temperature	±0.05~±0.5ppm(see the table)
		Vs. supply changes	±0.01ppm (Max) /Vdc±5%
		Vs. Ageing	±0.2~±0.5ppm/1 st year (Max)
output	Sinewave	Level	+10dBm/50 Ω
		Harmonics	≤-25dBc
		Non-Harmonic Suppression	≤-70dBc
Phase noise	10Hz 100MHz 1KHz 10KHz 100KHz The worse axis	Static	Vibration(methodB)
-100 dBc/Hz		See detail method	
-130 dBc/Hz		See detail method	
-155 dBc/Hz		-140dBc/Hz	
-165 dBc/Hz		-160dBc/Hz	
-170 dBc/Hz	-165dBc/Hz		
Operation temperature range		Different range(see the table)	
Input power		4W/1.8W(Max)@25℃	
Storage temperature range		-55~+85℃	
Dimension		40mm*40mm*20mm	

Frequency temperature Stability (ppm)

	± 0.05	± 0.1	± 0.2	± 0.5
0~50°C	JP	HP	GP	FP
-10~60°C	JQ	HQ	GQ	FQ
-20~70°C	JR	HR	GR	FR
-30~70°C	JS	HS	GS	FS
-40~70°C	JT	HT	GT	FT
-40~85°C			GU	FU
-55~85°C				FW

* please contact the factory

Outside frequency adjustment



with control voltage

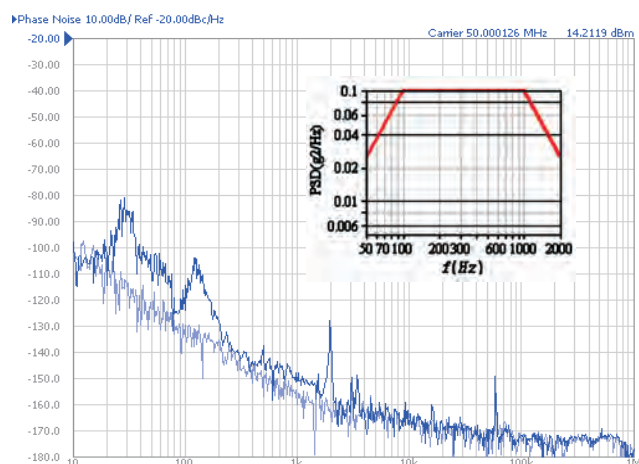
Absolute maximum ratings

Supply voltage--- $+16V$

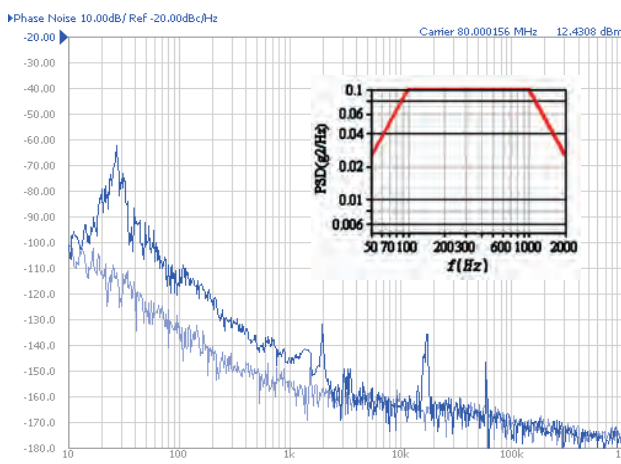
Storage temperature--- $+105$

Application notes please see OXK581 series

Note: The following phase noise are the worse one among three axis at 1KHz offset frequency



Phase noise vs. Offset frequency @50MHz/Random vibration method D RMS acceleration $G_{rms} = 11.95 \text{ g}$



Phase noise vs. Offset frequency @80MHz/Random vibration method D RMS acceleration $G_{rms} = 11.95 \text{ g}$